

December 1994

## 54F/74F00

## **Quad 2-Input NAND Gate**

### **General Description**

#### **Features**

This device contains four independent gates, each of which performs the logic NAND function.

■ Guaranteed 4000V minimum ESD protection

#### Ordering Code: See Section 0

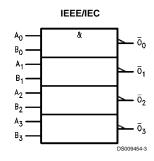
Commercial	Military	Package Package Description		
		Number		
74F00PC		N14A	14-Lead (0.300" Wide) Molded Dual-In-Line	
	54F00DM (Note 2)	J14A	14-Lead Ceramic Dual-In-Line	
74F00SC (Note 1)		M14A	14-Lead (0.150" Wide) Molded Small Outline, JEDEC	
74F00SJ (Note 1)		M14D	14-Lead (0.300" Wide) Molded Small Outline, EIAJ	
	54F00FM (Note 2)	W14B	14-Lead Cerpack	
	54F00LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C	

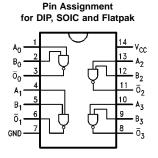
Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

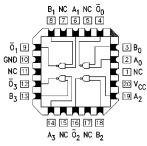
#### **Logic Symbol**

### **Connection Diagrams**





Pin Assignment for LCC



DS009454-1

DS009454-2

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# Unit Loading/Fan Out See Section 0 for U.L. definitions

		54F/74F				
Pin Name	s Description	U.L.	Input I <sub>IH</sub> /I <sub>IL</sub>			
		HIGH/LOW	Output I <sub>OH</sub> /I <sub>OL</sub>			
A <sub>n</sub> , B <sub>n</sub>	Inputs	1.0/1.0	20 μA/-0.6 mA			
<u>o</u>	Outputs	50/33.3	-1 mA/20 mA			

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#### **Absolute Maximum Ratings** (Note 3)

 $\begin{array}{lll} \mbox{Storage Temperature} & -65^{\circ}\mbox{C to } +150^{\circ}\mbox{C} \\ \mbox{Ambient Temperature under Bias} & -55^{\circ}\mbox{C to } +125^{\circ}\mbox{C} \\ \mbox{Junction Temperature under Bias} & -55^{\circ}\mbox{C to } +175^{\circ}\mbox{C} \\ \mbox{Plastic} & -55^{\circ}\mbox{C to } +150^{\circ}\mbox{C} \\ \end{array}$ 

 $V_{CC}$  Pin Potential to

Voltage Applied to Output

in HIGH State (with  $V_{CC} = 0V$ )

 $\begin{array}{lll} \mbox{Standard Output} & -0.5\mbox{V to V}_{\rm CC} \\ \mbox{TRI-STATE} \odot \mbox{Output} & -0.5\mbox{V to +5.5\mbox{V}} \end{array}$ 

Current Applied to Output

in LOW State (Max) twice the rated  $I_{\rm OL}$  (mA) ESD Last Passing Voltage (Min) 4000V

# Recommended Operating Conditions

Free Air Ambient Temperature

Commercial 0°C to +70°C

Supply Voltage

Commercial +4.5V to +5.5V

**Note 3:** Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions in act implied.

Note 4: Either voltage limit or current limit is sufficient to protect inputs.

#### **DC Electrical Characteristics**

Symbol	l Parameter		54F/74F			Units	V <sub>cc</sub>	Conditions		
			Min	Тур	Max	1				
V <sub>IH</sub>	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal		
V <sub>IL</sub>	Input LOW Voltage				0.8	V		Recognized as a LOW Signal		
V <sub>CD</sub>	Input Clamp Diode Voltage				-1.2	V	Min	I <sub>IN</sub> = -18 mA		
V <sub>OH</sub>	Output HIGH	54F 10% V <sub>CC</sub>	2.5					I <sub>OH</sub> = -1 mA		
	Voltage	74F 10% V <sub>CC</sub>	2.5			V	Min	I <sub>OH</sub> = -1 mA		
		74F 5% $V_{\rm CC}$	2.7					I <sub>OH</sub> = -1 mA		
V <sub>OL</sub>	Output LOW	54F 10% V <sub>CC</sub>			0.5	V	Min	I <sub>OL</sub> = 20 mA		
	Voltage	74F 10% V <sub>CC</sub>			0.5			I <sub>OL</sub> = 20 mA		
I <sub>IH</sub>	Input HIGH	54F			20.0	μΑ	Max	V <sub>IN</sub> = 2.7V		
	Current	74F			5.0					
I <sub>BVI</sub>	Input HIGH Current	54F			100	μΑ	Max	V <sub>IN</sub> = 7.0V		
	Breakdown Test	74F			7.0					
I <sub>CEX</sub>	Output HIGH	54F			250	μA	Max	V <sub>OUT</sub> = V <sub>CC</sub>		
	Leakage Current	74F			50					
V <sub>ID</sub>	Input Leakage	74F	4.75			V	0.0	I <sub>ID</sub> = 1.9 μA		
	Test							All other pins grounded		
I <sub>OD</sub>	Output Leakage	74F			3.75	μA	0.0	V <sub>IOD</sub> = 150 mV		
	Circuit Current							All other pins grounded		
I <sub>IL</sub>	Input LOW Current				-0.6	mA	Max	V <sub>IN</sub> = 0.5V		
Ios	Output Short-Circuit Current		-60		-150	mA	Max	V <sub>OUT</sub> = 0V		
I <sub>CCH</sub>	Power Supply Current			1.9	2.8	mA	Max	V <sub>O</sub> = HIGH		
I <sub>CCL</sub>	Power Supply Currer		6.8	10.2	mA	Max	V <sub>O</sub> = LOW			

#### **AC Electrical Characteristics**

See Section 0 for Waveforms and Load Configurations

	Parameter	74F T <sub>A</sub> = +25°C V <sub>CC</sub> = +5.0V C <sub>L</sub> = 50 pF			54F T <sub>A</sub> , V <sub>CC</sub> = Mil C <sub>L</sub> = 50 pF		74F T <sub>A</sub> , V <sub>CC</sub> = Com C <sub>L</sub> = 50 pF		Units	Fig.
Symbol										
		Min	Тур	Max	Min	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	2.4	3.7	5.0	2.0	7.0	2.4	6.0	ns	<b>**-*</b>
t <sub>PHL</sub>	$A_n$ , $B_n$ to $\overline{O}_n$	1.5	3.2	4.3	1.5	6.5	1.5	5.3		

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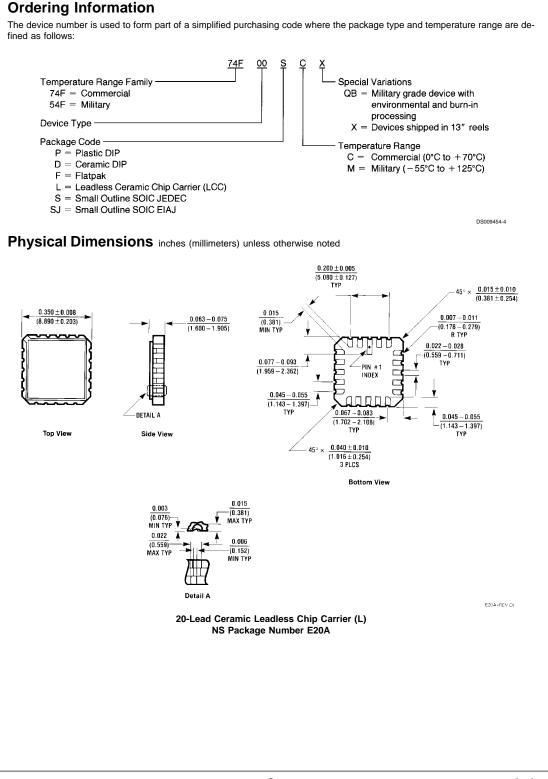
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DSXXX

Extract

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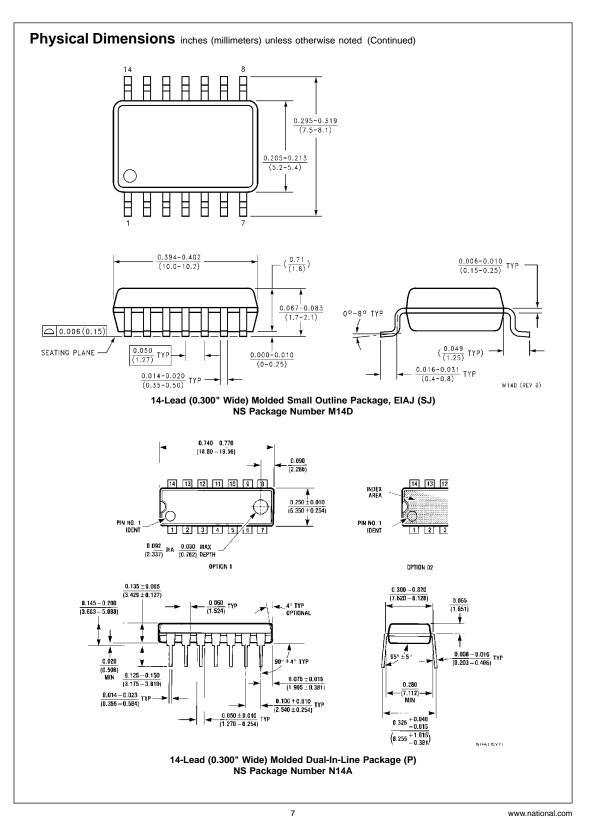


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#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 0.785 (19.939) MAX 14 13 12 11 10 9 8 0.025 (0.635)0.220-0.310 RAD (5.588-7.874) 1 2 3 4 5 6 7 0.290-0.320 0.005 0.200 (0.127) MIN GLASS (7.366-8.128) 0.060 ±0.005 (5.080)MAX 0.020-0.060 SEALANT (1.524 ±0.127) 0.180 (0.508-1.524) MAX (4.572)86°94° TYP 0.008-0.012 10° MAX (0.203-0.305) 0.310-0.410 $0.018 \pm 0.003$ 0.125-0.200 0.098 (7.874-10.41) (0.457 ±0.076) (3.175-5.080) (2.489) 0.100 ±0.010 MAX BOTH ENDS 0.150 (2.540 ±0.254) (3.81) MIN J14A (REV G) 14-Lead Ceramic Dual-In-Line Package (D) NS Package Number J14A 0.335 - 0.344 (8.509 - 8.738) $\frac{0.228 - 0.244}{(5.791 - 6.198)}$ LEAD NO. 1 0.010 (0.254) MAX $\frac{0.150 - 0.157}{(3.810 - 3.988)}$ $\frac{0.053 - 0.069}{(1.346 - 1.753)}$ 0.010 - 0.020 (0.254 - 0.508) 8° MAX TYP $\frac{0.004 - 0.010}{(0.102 - 0.254)}$ ALL LEADS SEATING PLANE 0.014 0.008 - 0.010 (0.203 - 0.254) TYP ALL LEADS $-\frac{0.014 - 0.020}{(0.356 - 0.508)}$ TYP 0.016 - 0.050 0.004 (0.102) ALL LEAD TIPS (0.406 - 1.270) TYP ALL LEADS $-\frac{0.008}{(0.203)}$ TYP MI4A (REV H)

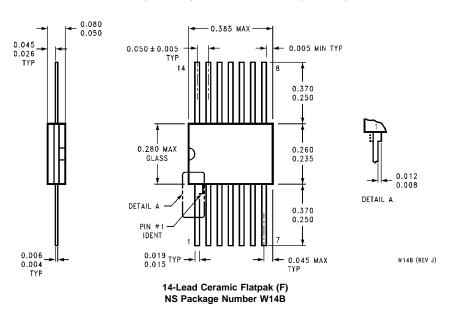
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14-Lead (0.150" Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M14A



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#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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